

100mA, 75V Switching Diode

FEATURES

- Low power loss, high efficiency
- · Ideal for automated placement
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

- Case: 0603(Ceramics)
- Molding compound meets UL flammability classification rating 94HB
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 2.7 mg (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	100	mA		
V_{RRM}	75	V		
I _{FSM}	0.8	Α		
V _F at I _F =10mA V _F at I _F =100mA	1.00 1.25	V		
T _J Max.	150	°C		
Package	0603 (Ceramics)			
Configuration	Single die			









ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage	V_{RRM}	75	V		
Mean forward current	I _F	100	mA		
Non-repetitive peak forward surge	at t<1s		0.4	Α	
current	at t≦8.3ms	IFSM	0.8		
Junction temperature range	T _J	-55 to +150	°C		
Storage temperature range	T _{STG}	-55 to +150	°C		

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THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP.	UNIT		
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	375	°C/W		

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Forward voltage per diode (1)	I _F =10mA, T _J =25°C		-	1.00	V	
	I _F =100mA, T _J =25°C	V _F	-	1.25		
Reverse current @ rated V _R per	V _R =20V T _J =25°C		-	25	nA	
diode (2)	V _R =75V T _J =25°C	– I _R	-	5	μA	
Reverse recovery time	$I_F=10mA$, $I_R=10mA$, $R_L=100\Omega$	t _{rr}	-	4	ns	
Junction capacitance	1 MHz, V _R =0V	Сл	-	4	pF	

Notes:

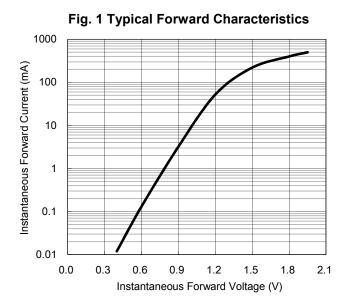
- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION					
ORDERING CODE	PACKING				
TS4148C RZG	0000	5K / 7" Reel			
TS4148C RCG	0603	10K / 13" Reel			



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)



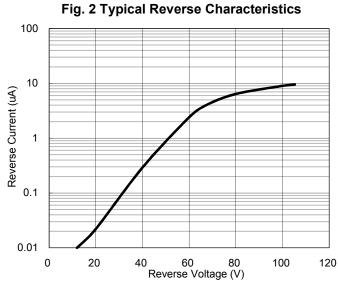


Fig. 3 Admissible Power Dissipation Curve

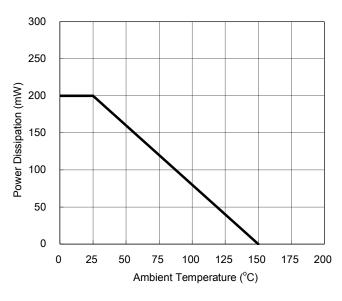
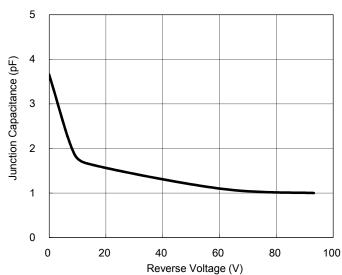


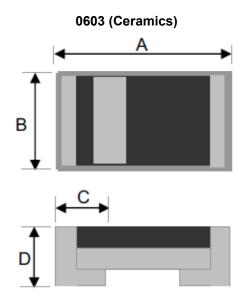
Fig. 4 Typical Junction Capacitance





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PACKAGE OUTLINE DIMENSION



DIM	Unit (mm)		Unit (inch)		
DIM.	Min	Max	Min	Max	
Α	1.45	1.65	0.057	0.065	
В	0.70	0.90	0.028	0.035	
С	0.25	0.45	0.010	0.018	
D	0.55	0.75	0.022	0.030	





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